Diode Semiconductor Device - Page 1 of 1



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Inclosure Materia	
Glass	
Overall Length:	
3etween 0.195 inc	hes and 0.350 inches
Terminal Length:	
1.000 inches	
Overall Diameter:	
Between 0.215 inc	hes and 0.265 inches
Electrode Interna	Ily-electrically Connected To Case:
Cathode	
Mounting Method	I:
Terminal	
Features Provide	d:
Hermetically seale	d case
Semiconductor N	laterial:
Silicon	
Voltage Rating In	Volts Per Characteristic:
4.7 regulator volta	age
Current Rating Pe	er Characteristic:
194.00 milliampere	es source cutoff current horsepower metric
Power Rating Per	Characteristic:
1.0 watts small-sig	nal input power, common-collector preset
Maximum Operat	ing Tempurature Per Measurement Point:
175.0 degrees cels	sius ambient air
Test Data Docum	ent:
31349-mil-s-19500) specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
iormat; excludes o	commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and	performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type Ar	nd Quantity:
2 uninsulated wire	lead
Specification Dat	a:
81349-mil-s-19500)/115 government specification
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	